

## TENTATIVE

TOSHIBA Photocoupler GaAlAs Ired + Photo IC

# TLP759(IGM)

Transistor Invertor

Inverter For Air Conditioner

Line Receiver

IPM Interfaces

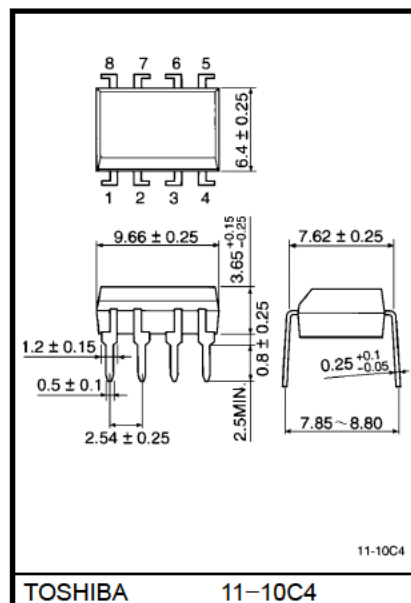
The TOSHIBA TLP759(IGM) consists of a GaAlAs high-output light emitting diode and a high speed detector of one chip photo diode-transistor.

This unit is 8-lead DIP.

TLP759(IGM) has no internal base connection, and a faraday shield integrated on the photodetector chip provides an effective common mode noise transient immunity.

TLP759(IGM) guarantees minimum and maximum of propagation delay time, switching time dispersion, and high common mode transient immunity. Therefore TLP759(IGM) is suitable for isolation interface between IPM(intelligent power module) and control IC circuits in motor control application.

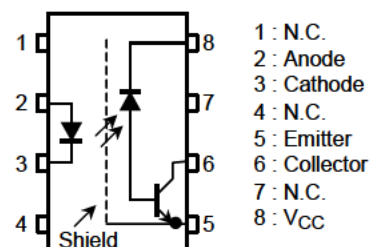
Unit in mm



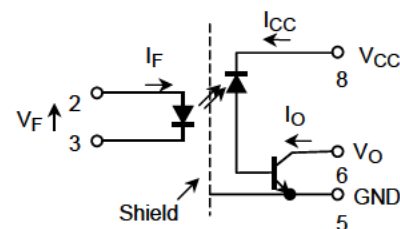
Weight: 0.54 g

- Isolation voltage: 5000V<sub>rms</sub> (min.)
- Common mode transient immunity  
: ±10kV / μs (min.)  
@V<sub>CM</sub> = 1500 V
- Switching Time  
: t<sub>pHL</sub>, t<sub>pLH</sub> = 0.1μs (min.)  
= 0.8μs (max.)  
@I<sub>F</sub> = 10mA, V<sub>CC</sub> = 15V, R<sub>L</sub> = 20kΩ, T<sub>a</sub> = 25°C
- Switching time dispersion: 0.7μs (max.)  
(|t<sub>pLH</sub> - t<sub>pHL</sub>|)
- TTL compatible
- UL recognized: UL1577, file no.E67349

## Pin Configuration(top view)



## Schematic



- Option (D4) type  
VDE approved: DIN VDE0884 / 06.92,  
Maximum operating insulation voltage: 890V<sub>PK</sub>  
Highest permissible over voltage: 6000V<sub>PK</sub>

**(Note 1) When a VDE0884 approved type is needed,  
please designate the “Option (D4)”**

- Structural parameter      7.62mm pitch TLP759 (IGM)  
Creepage distance: 7.0mm (min.)  
Clearance: 7.0mm (min.)  
Insulation thickness: 0.4mm (min.)

## Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
LED	Forward current (Note 2)	I <sub>F</sub>	25	mA
	Pulse forward current (Note 3)	I <sub>FP</sub>	50	mA
	Peak transient forward current (Note 4)	I <sub>FPT</sub>	1	A
	Reverse voltage	V <sub>R</sub>	5	V
	Diode power dissipation (Note 5)	P <sub>D</sub>	45	mW
Detector	Output current	I <sub>O</sub>	8	mA
	Peak output current	I <sub>OP</sub>	16	mA
	Output voltage	V <sub>O</sub>	−0.5~20	V
	supply voltage	V <sub>CC</sub>	−0.5~30	V
	Output power dissipation (Note 6)	P <sub>O</sub>	100	mW
Operating temperature range		T <sub>opr</sub>	−55~100	°C
Storage temperature range		T <sub>stg</sub>	−55~125	°C
Lead solder temperature(10s) (Note 7)		T <sub>sol</sub>	260	°C
Isolation voltage(AC,1min.,R.H.≤60%,Ta=25°C) (Note 8)		BV <sub>S</sub>	5000	V <sub>rms</sub>

(Note 2): Derate 0.8mA above 70°C.

(Note 3): 50% duty cycle, 1ms pulse width.

Derate 1.6mA / °C above 70°C.

(Note 4): Pulse width PW ≤ 1μs, 300pps.

(Note 5): Derate 0.9mW / °C above 70°C.

(Note 6): Derate 2mW / °C above 70°C.

(Note 7): Soldering portion of lead: Up to 2mm from the body of the device.

(Note 8): Device considered a two terminal device: Pins 1, 2, 3 and 4 shorted together and  
pins 5, 6, 7 and 8 shorted together.

**Electrical Characteristics (Ta = 25°C)**

Characteristic		Symbol	Test Condition	Min.	Typ.	Max.	Unit
LED	Forward voltage	$V_F$	$I_F = 16\text{mA}$		1.65	1.85	V
	Forward voltage temperature coefficient	$\Delta V_F / \Delta T_a$	$I_F = 16\text{mA}$	—	-2	—	mV / °C
	Reverse current	$I_R$	$V_R = 5\text{V}$	—	—	10	$\mu\text{A}$
	Capacitance between terminal	$C_T$	$V_F = 0, f = 1\text{MHz}$	—	45	—	pF
Detector	High level output current	$I_{OH(1)}$	$I_F = 0\text{mA}, V_{CC} = V_O = 5.5\text{V}$	—	3	500	nA
		$I_{OH(2)}$	$I_F = 0\text{mA}, V_{CC} = 30\text{V}$ $V_O = 20\text{V}$	—	—	5	$\mu\text{A}$
		$I_{OH}$	$I_F = 0\text{mA}, V_{CC} = 30\text{V}$ $V_O = 20\text{V}, T_a = 70^\circ\text{C}$	—	—	50	
	High level supply voltage	$I_{CCH}$	$I_F = 0\text{mA}, V_{CC} = 30\text{V}$	—	0.01	1	$\mu\text{A}$
	Supply voltage	$V_{CC}$	$I_{CC} = 0.01\text{mA}$	30	—	—	V
	Output voltage	$V_O$	$I_O = 0.5\text{mA}$	20	—	—	V

**Coupled Electrical Characteristics (Ta = 25°C)**

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Current transfer ratio	$I_O / I_F$	$I_F = 10\text{mA}, V_{CC} = 4.5\text{V}$ $V_O = 0.4\text{V}$	25	35	75	%
		$I_F = 16\text{mA}, V_{CC} = 4.5\text{V}$ $V_O = 0.4\text{V}, T_a = -25 \sim 100^\circ\text{C}$	15	—	—	
Low level output voltage	$V_{OL}$	$I_F = 16\text{mA}, V_{CC} = 4.5\text{V}$ $I_O = 2.4\text{mA}$	—	—	0.4	V

**Isolation Characteristics (Ta = 25°C)**

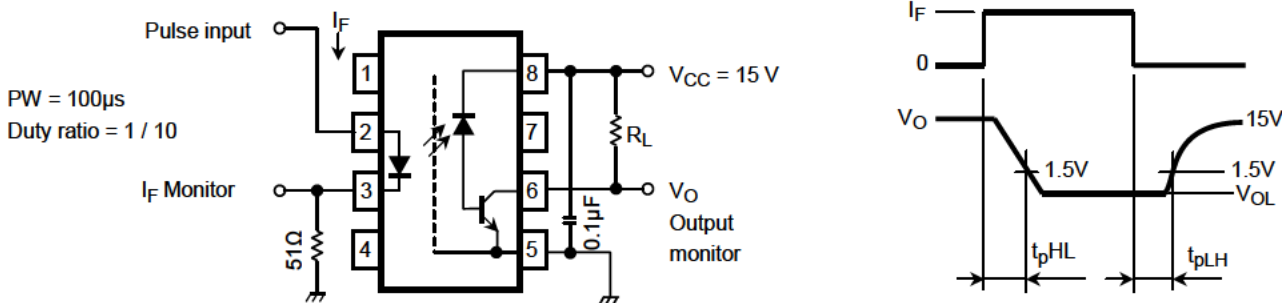
Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Capacitance input to output	$C_S$	$V = 0, f = 1\text{MHz}$ (Note 8)	—	0.8	—	pF
Isolation resistance	$R_S$	R.H. $\leq 60\%$ , $V_S = 500\text{V}$ (Note 8)	$1 \times 10^{12}$	$10^{14}$	—	$\Omega$
Isolation voltage	$BV_S$	AC, 1 minute	5000	—	—	$V_{rms}$
		AC, 1 second, in oil	—	10000	—	Vdc
		DC, 1 minute, in oil	—	10000	—	

**Switching Characteristics (Ta = 25°C, Vcc = 15V)**

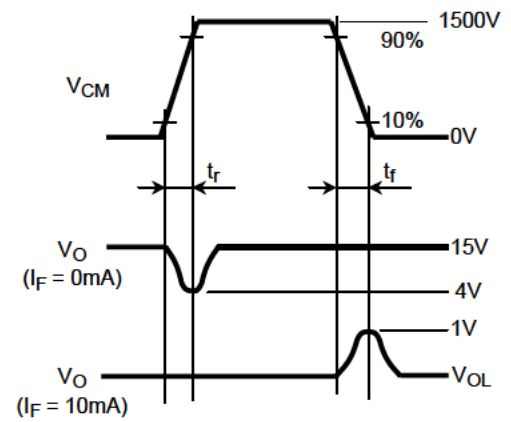
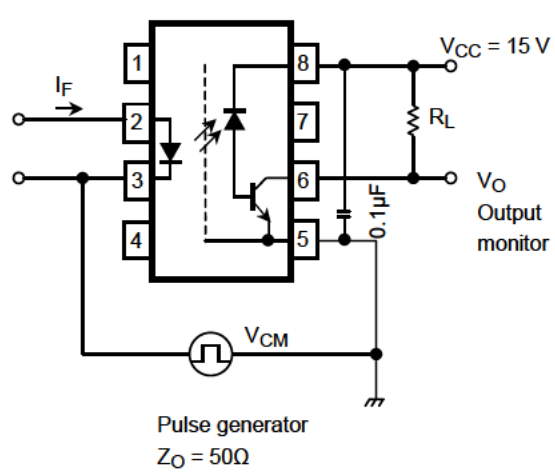
Characteristic	Symbol	Test Cir- cuit	Test Condition	Min.	Typ.	Max.	Unit
Propagation delay time (H→L)	t <sub>pHL</sub>	1	I <sub>F</sub> = 10mA, R <sub>L</sub> = 20kΩ	0.1	0.45	0.8	μs
Propagation delay time (L→H)	t <sub>pLH</sub>		I <sub>F</sub> = 10mA, R <sub>L</sub> = 20kΩ Ta = 0~85°C	0.1	0.45	0.9	
			I <sub>F</sub> = 10mA, R <sub>L</sub> = 20kΩ Ta = -25~100°C	0.1	0.45	1.0	
Switching time dispersion between on and off	t <sub>pLH</sub> -t <sub>pHL</sub>		I <sub>F</sub> = 10mA, R <sub>L</sub> = 20kΩ	—	0.15	0.7	μs
			I <sub>F</sub> = 10mA, R <sub>L</sub> = 20kΩ Ta = 0~85°C	—	0.25	0.8	
			I <sub>F</sub> = 10mA, R <sub>L</sub> = 20kΩ Ta = -25~100°C	—	0.25	0.9	
Common mode transient immunity at logic high output (Note 9)	CM <sub>H</sub>	2	I <sub>F</sub> = 0mA V <sub>CM</sub> = 1500V <sub>p-p</sub> R <sub>L</sub> = 20kΩ	10000	15000	—	V / μs
Common mode transient immunity at logic low output (Note 9)	CM <sub>L</sub>		I <sub>F</sub> = 10mA V <sub>CM</sub> = 1500V <sub>p-p</sub> R <sub>L</sub> = 20kΩ	-10000	-15000	—	V / μs

(Note 9):  $CM_L$  is the maximum rate of fall of the common mode voltage that can be sustained with the output voltage in the logic low state ( $V_O < 1V$ ).  
 $CM_H$  is the maximum rate of rise of the common mode voltage that can be sustained with the output voltage in the logic high state ( $V_O < 4V$ ).  
 (Note 10): Maximum electrostatic discharge voltage for any pins: 100V(C = 200pF, R = 0).

**Test Circuit 1: Switching Time Test Circuit**



**Test Circuit 2: Common Mode Noise Immunity Test Circuit**



$$CM_{IH} = \frac{1200(V)}{t_r(\mu s)}, CM_{IL} = \frac{1200(V)}{t_f(\mu s)}$$

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